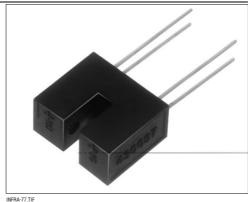
### **Transmissive Sensor**

#### **FEATURES**

- Choice of phototransistor or photodarlington output
- Wide operating temperature range (- 55°C to +100°C)
- · Accurate position sensing
- 0.100 in.(2.54 mm) slot width



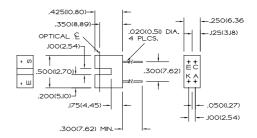
#### DESCRIPTION

The HOA2862 series consists of an infrared emitting diode facing an NPN silicon phototransistor (HOA2862-001, -002) or photodarlington (HOA2862-003) encased in a black thermoplastic housing. Detector switching takes place whenever an opaque object passes through the slot between emitter and detector. The HOA2862 series employs metal can packaged components and has a 0.025 in.(.635 mm) x 0.040 in.(1.02 mm) vertical aperture in front of the detector. The narrow detector aperture is ideal for use in applications in which the maximum rejection of ambient light is important. For additional component information see SE1450, SD1440, and SD1410.

Housing material is polyester. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

#### OUTLINE DIMENSIONS in inches (mm)

3 plc decimals ±0.010(0.25) 2 plc decimals ±0.020(0.51)



DIM\_058.cdr



### **Transmissive Sensor**

#### ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	VF			1.6	V	I <sub>F</sub> =20 mA
Reverse Leakage Current	IR			10	μΑ	V <sub>R</sub> =3 V
DETECTOR						
Collector-Emitter Breakdown Voltage	V <sub>(BR)</sub> ceo				V	Ic=100 μA
HOA2862-001, -002		30				
HOA2862-003		15				
Emitter-Collector Breakdown Voltage	V <sub>(BR)ECO</sub>	5.0			V	I <sub>E</sub> =100 μA
Collector Dark Current	ICEO				nA	V <sub>CE</sub> =10 V
HOA2862-001, -002				100		I <sub>F</sub> =0
HOA2862-003				250		
COUPLED CHARACTERISTICS						
On-State Collector Current	I <sub>C</sub> (ON)				mA	V <sub>CE</sub> =5 V
HOA2862-001		0.2				I <sub>F</sub> =20 mA
HOA2862-002		1.8				
HOA2862-003		4.0				
Collector-Emitter Saturation Voltage	VCE(SAT)				V	I <sub>F</sub> =20 mA
HOA2862-001				0.4		lc=25 μA
HOA2862-002				0.4		Ic=75 μA
HOA2862-003				1.1		Ic=500 μA
Rise And Fall Time	t <sub>r</sub> , t <sub>f</sub>				μs	Vcc=5 V, lc=1 mA
HOA2862-001, -002			15			R <sub>L</sub> =1000 Ω
HOA2862-003			75			R <sub>L</sub> =100 Ω

#### **ABSOLUTE MAXIMUM RATINGS**

(25°C Free-Air Temperature unless otherwise noted)

Operating Temperature Range -55°C to 100°C

Storage Temperature Range -55°C to 125°C

Soldering Temperature (10 sec) 260°C

oldering Temperature (10 sec) 260°C

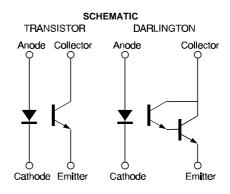
**IR EMITTER**Power Dissipation 75 mW <sup>(1)</sup>
Reverse Voltage 3 V

Continuous Forward Current 50 mA

DETECTOR TRANS. DARLINGTON

Collector-Emitter Voltage 30 V 15 V

Emitter-Collector Voltage 5 V 5 V
Power Dissipation 75 mW (1) 75 mW (1)
Collector DC Current 30 mA 30 mA

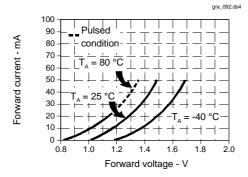


Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

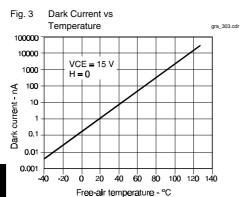
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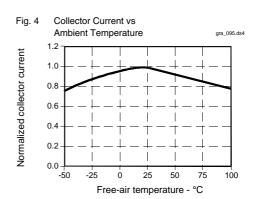
### **Transmissive Sensor**





Non-Saturated Switching Time vs Load Resistance 1000 ▤◾▦▦ Response time - µs 100 Photodarlington = = = = Phototransistor ŦI#I# 10 100 1000 10000 Load resistance - Ohms





All Performance Curves Show Typical Values

**Transmissive Sensor**